



Ultrahigh-Speed Switching Applications

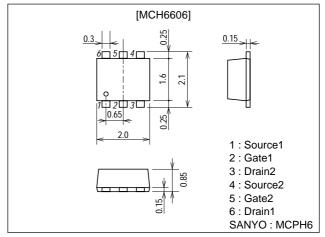
Features

- · Low ON resistance.
- · Ultrahigh-speed swithcing.
- · 4V drive.
- · Composite type with 2 MOSFETs contained in one package, facilitating high-density mounting.

Package Dimensions

unit:mm

2173



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		50	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		0.25	Α
Drain Current (pulse)	I _{DP}	PW≤10µs, duty cycle≤1%	1	Α
Allowable Power Dissipation	P _D	Mounted on a ceramic board (900mm ² ×0.8mm) 1unit	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Uill
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0	50			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =50V, V _{GS} =0			10	μA
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =100μA	1		2.4	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =50mA	85	120		mS
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =50mA, V _{GS} =10V		5.8	7.5	Ω
	R _{DS} (on)2	I _D =30mA, V _{GS} =4V		7.5	10.5	Ω
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		6.2		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		4.4		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		1.5		pF

- Marking: FF Continued on next page.
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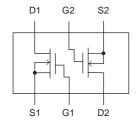
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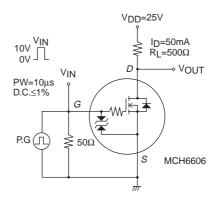
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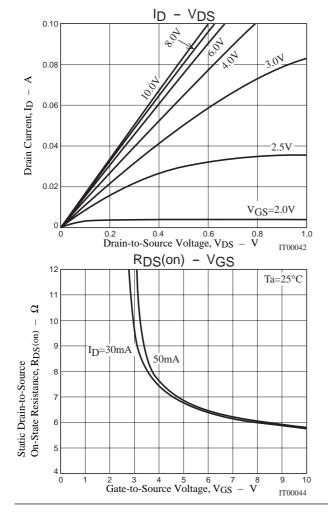
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Uill
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		10		ns
Rise Time	t _r	See specified Test Circuit		11		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		105		ns
Fall Time	t _f	See specified Test Circuit		75		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =100mA		1.40		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =100mA		0.21		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =100mA		0.34		nC
Diode Forward Voltage	V _{SD}	I _S =100mA, V _{GS} =0		0.85	1.2	V

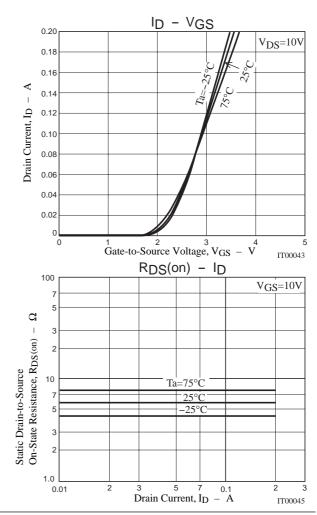
Electrical Connection

Switching Time Test Circuit

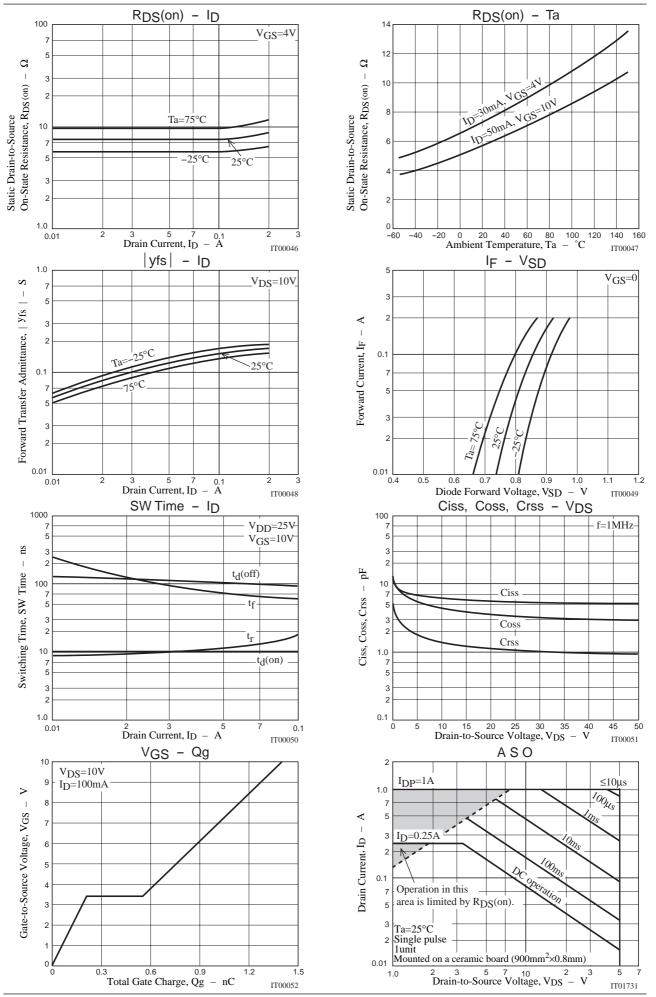




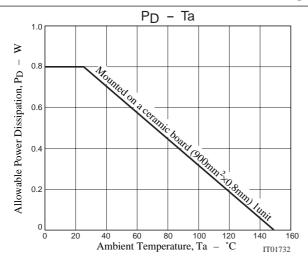




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